PCN Num	ber:	202	2203	303000.1		PC	N E	Date:	March 09, 2022		
Title:	Qualification	of R	FAB	as an additio	nal Fab site o	optic	option for select LBC8 devices				
Customer	Contact:		PCN	N Manager		De	pt:		Quality Services		
Proposed	1 st Ship Date	e:	Jun	9, 2022	Estimated S Availability		ıplo	е	Date provided at sample request.		
Change T	уре:										
Asser	nbly Site			Assembly Pro	ocess			Assem	bly Materials		
Desig	n			Electrical Spe	ecification			Mecha	nical Specification		
Test 9	Site			Packing/Ship	pping/Labeling	g		Test P	rocess		
Wafei	r Bump Site			Wafer Bump	Material			Wafer	Bump Process		
	r Fab Site		Wafer Fab Materials					Wafer	Fab Process		
			Part number change								

Notification Details

Description of Change:

Texas Instruments is pleased to announce the qualification of its RFAB fabrication facility as an additional Wafer Fab source for the selected devices listed in the "Product Affected" section.

Cu	rrent Fab Sit	е	A	dditional Fab	Site
Current Fab Site	Process	Wafer Diameter	New Fab Site	Process	Wafer Diameter
MIHO8	LBC8	200 mm	RFAB	LBC8	300 mm

Qual details are provided in the Qual Data Section.

Reason for Change:

Continuity of supply

Anticipated impact on Fit, Form, Function, Quality or Reliability (positive / negative):

None

Changes to product identification resulting from this PCN:

Fab Site Information:

RFAB	RFB	USA	Richardson
MIHO8	MH8	JPN	Ibaraki
Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City

Sample product shipping label (not actual product label)



5A (L)T0:1750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483S12 (P) (2P) REV: (20L) CSO: SHE (21L) CCO: USA (22L) ASO: MEA (23L) ACO: MYS

Product Affected:

SN21220ADR	UCC21220HDR	UCC21540DW	UCC21542ADWKR
SN21220DR	UCC21222D	UCC21540DWK	UCC21542DWKR
UCC21220AD	UCC21222DR	UCC21540DWKR	UCC21542DWR

UCC21220ADR	UCC21540ADWK	UCC21540DWR	UCC5304DWV
UCC21220D	UCC21540ADWKR	UCC21541DW	UCC5304DWVR
UCC21220DR	UCC21540ADWR	UCC21541DWR	

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approve Date 23-FEBRUARY -2022

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name	Condition	Duration	Qual Device: UCC21222QDQ1	Qual Device: UCC21540QDWKRQ1	Qual Device: UCC21540DWR	Qual Device: UCC5304DWV	QBS Reference: UCC23513QDWYQ1	QBS Reference: UCC21540DWR
Test G	roup A -	Accelerated	Environ	ıment St	ress Tests								
PC	A1	JEDEC J-STD- 020 JESD22- A113	3	77	Preconditioning	MSL2 260C	-	No Fails	No Fails	-	-	No Fails	-
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	-	-	-	-	3/231/0	-
AC	А3	JEDEC JESD22- A102	3	77	Autoclave	121C/15psig	96 Hours	1/77/0	-	-	-	3/231/0	-
TC	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-85C/150C	500 Cycles	1/77/0	1/77/0	-	-	3/231/0	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temp Storage Bake	175C	500 Hours	-	-	-	-	3/231/0	-
Test G	roup B -	Accelerated	Lifetime	e Simula	tion Tests								
HTOL	В1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours	-	-	-	-	3/231/0	1/77/0 (1)
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	125C	48 Hours	-	-	-	-	3/2400/0	-
Test G	roup C -	Package As	sembly	Integrity	Tests								
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.87	Wires	1/30/0	1/30/0	-	-	3/90/0	-
WBP	C2	MIL- STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.87	Wires	1/30/0	1/30/0	-	-	3/90/0	-
SD	C3	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-	-	-	-	1/15/0	-
SD	C3	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	-	-	1/15/0	-
PD	G4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	1/10/0	1/10/0	-	-	3/30/0	-

Test G	roup D -	Die Fabricat	ion Relia	ability Te	ests								
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test G	roup E -	Electrical Ve	rificatio	n Tests									
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	1/3/0	1/3/0	-	-	1/3/0	-
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	1/3/0	1/3/0	-	-	1/3/0	-
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	1/6/0	-	-	1/6/0	-
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	1/30/0	1/30/0	-	-	3/90/0	-

Test Gr	oup A	Accelerated	l I Envir <u>or</u>	nment <u>S</u>	tress Tests								
PC	A1	JEDEC J-STD- 020 JESD22- A113	3	77	Preconditioning	MSL2 260C		No Fails	No Fails	-	-	No Fails	-
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	-	-	-	-	3/231/0	-
AC	А3	JEDEC JESD22- A102	3	77	Autoclave	121C/15psig	96 Hours	1/77/0	-	-	-	3/231/0	-
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	1/77/0	1/77/0	-	-	3/231/0	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temp Storage Bake	175C	500 Hours	-	-	-	-	3/231/0	-
Test Gr	oup B -	Accelerated	Lifetim	e Simula	tion Tests								
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours	-	-	-	-	3/231/0	1/77/0 (1)
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	125C	48 Hours	-	-	-	-	3/2400/0	-
Test Gr	oup C - I	Package As	sembly	Integrity	Tests								
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	1/30/0	-	-	3/90/0	-
WBP	C2	MIL- STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	1/30/0	-	-	3/90/0	-
SD	СЗ	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-	-	-	-	1/15/0	-
SD	С3	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	-	-	1/15/0	-
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	1/10/0	1/10/0	-	-	3/30/0	-

QBS: Qual By Similarity

- Qual Device UCC21222QDQ1 is qualified at MSL3 260C
- Qual Device UCC21540QDWKRQ1 is qualified at MSL3 260C
- Qual Device UCC21540DWR is qualified at MSL2 260C
- Qual Device UCC5304DWV is qualified at MSL2 280C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -85C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- . Room/Hot/Cold : HTOL, ED
- . Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Notes:

(1) Automotive Grade 1 condition used for HTOL

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approve Date 23-FEBRUARY -2022

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name	Condition	Duration	Qual Device: UCC21222QDQ1	Qual Device: UCC21540QDWKRQ1	QBS Reference: UCC21520QDWRQ1	QBS Reference: UCC23513QDWYQ1	QBS Reference: ISO7741FEDWRQ1	QB\$ Reference: UCC21530QDWKRQ1
Test Gr	oup A - A	Accelerated	I Enviror	ment St	ress Tests								·
PC	A1	JEDEC J-STD- 020	3	77	Preconditioning	MSL2 260C	-	-	-	-	No Fails	No Fails	No Fails
		JESD22- A113											
PC	A1	JEDEC J-STD- 020 JESD22- A113	3	77	Preconditioning	MSL3 260C	-	No Fails	No Fails	No Fails	-	-	-
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	-	-	3/231/0	3/231/0	3/231/0	-
AC	А3	JEDEC JESD22- A102	3	77	Autoclave	121C, 15psig	96 Hours	-	1/77/0	-	3/231/0	3/231/0	3/231/11
AC	А3	JEDEC JESD22- A102	3	77	Unbiased HAST	130C/85%RH	98 Hours	-	-	3/231/0	-	-	-
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	2000 Cycles	-	-	-	-	3/231/0	
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	1/77/0	1/77/0	-	3/231/0	3/231/0	3/231/11
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	1000 Hours	-	-	-	3/135/0	3/135/0	-
Test G	roup B -	Accelerated	Lifetim	e Simula	tion Tests								
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours	-	-	3/231/0	3/231/0	-	-
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	150C	1000 Hours	-	-	-	-	3/231/0	-
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	125C	48 Hours	-	-	-	3/2400/0		-
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	150C	48 Hours	-	-	-	-	3/2400/0	-
Test G	roup C -	Package As	sembly	Integrity	Tests								
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	1/30/0	3/90/0	3/90/0	3/90/0	3/90/0
WBP	C2	MIL- STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	1/30/0	3/90/0	3/90/0	3/90/0	3/90/0
SD	C3	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-	-	1/15/0	1/15/0	1/15/0	-
SD	С3	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	1/15/0	1/15/0	1/15/0	-
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	1/10/0	1/10/0	3/30/0	3/30/0	3/30/0	3/30/0
Test Gr	roup D -	Die Fabricat	tion Reli	ability Te	ests								
ЕМ	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements

NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Gr	roup E - I	Electrical Ve	erificatio	n Tests									
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	-	-	1/3/0	1/3/0	1/3/0	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	-	-	1/3/0	1/3/0	1/3/0	1/3/0
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	-	-	1/6/0	1/6/0	1/6/0	1/6/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	-	-	3/90/0	3/90/0	3/90/0	3/90/0
Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name	Condition	Duration	Qual Device	Qual Device	QBS Reference	QBS Reference	QBS Reference	QBS Reference

- QBS: Qual By Similarity
 Qual Device UCC21222QDQ1 is qualified at MSL3 280C
 Qual Device UCC21540QDWKRQ1 is qualified at MSL3 280C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV|: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- Room/Hot/Cold : HTOL_ED
- Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

[1]-Contact TI Quality group for 8D report.

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approve Date 23-FEBRUARY -2022

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: SN21222QDRQ1	QBS Reference: UCC21222QDQ1	QBS Reference: UCC23513QDWYQ1	QBS Reference: UCC21540DWR
Test G	roup A -	Accelerated	l Enviro	nment St	tress Tests						
PC	A1	JEDEC J-STD- 020 JESD22- A113	3	77	Preconditioning	MSL2 260C	-	-	No Fails	No Fails	-
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	-	-	3/231/0	-
AC	A3	JEDEC JESD22- A102	3	77	Autoclave	121C/15psig	96 Hours	-	1/77/0	3/231/0	-
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	-	1/77/0	3/231/0	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temp Storage Bake	175C	500 Hours	-	-	3/231/0	-

Test G	oup B -	Accelerated	Lifetime	e Simula	tion Tests						
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours	-	-	3/231/0	1/77/0 ⁽¹⁾
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	125C	48 Hours	-	-	3/2400/0	-
Test G	oup C -	Package As	sembly I	Integrity	Tests						
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30	Wires	-	1/30/0	3/90/0	-
						wires Cpk>1.67					
WBP	C2	MIL- STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	-	1/30/0	3/90/0	-
SD	C3	JEDEC JESD22- B102	1	15	PB Solderability	>95% Lead Coverage	-	-	-	1/15/0	-
SD	C3	JEDEC JESD22- B102	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	1/15/0	-
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	-	1/10/0	3/30/0	-
Test G	oup D -	Die Fabricat	ion Relia	bility Te	sts						
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Carrier Injection	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test G	roup E -	Electrical V	erificatio	n Tests							
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	-	1/3/0	1/3/0	-
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	-	1/3/0	1/3/0	-
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	-	1/6/0	1/6/0	-
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	-	1/30/0	3/90/0	-
Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device	QBS Reference	QBS Reference	QBS Reference

- QBS: Qual By Similarity
 Qual Device SN21222QDRQ1 is qualified at MSL3 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
 The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

- Grade 0 (or E): -40C to +150C
- Grade 1 (or Q): -40C to +125C
- Grade 2 (or T): -40C to +105C
- Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

- · Room/Hot/Cold : HTOL, ED
- . Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU
- Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Notes:

(1) Automotive Grade 1 condition used for HTOL.

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
WW PCN Team	PCN www admin_team@list.ti.com

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